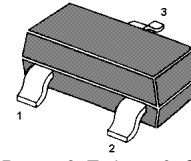


BCV27 / BCV47

NPN Darlington Transistors

for preamplifier input applications



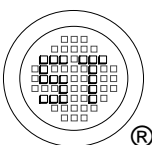
1. Base 2. Emitter 3. Collector
SOT-23 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	BCV27 BCV47 V_{CBO}	40 80	V
Collector Emitter Voltage	BCV27 BCV47 V_{CEO}	30 60	V
Emitter Base Voltage	V_{EBO}	10	V
Collector Current	I_C	500	mA
Peak Collector Current	I_{CM}	800	mA
Base Current	I_B	100	mA
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 65 to + 150	$^\circ\text{C}$

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

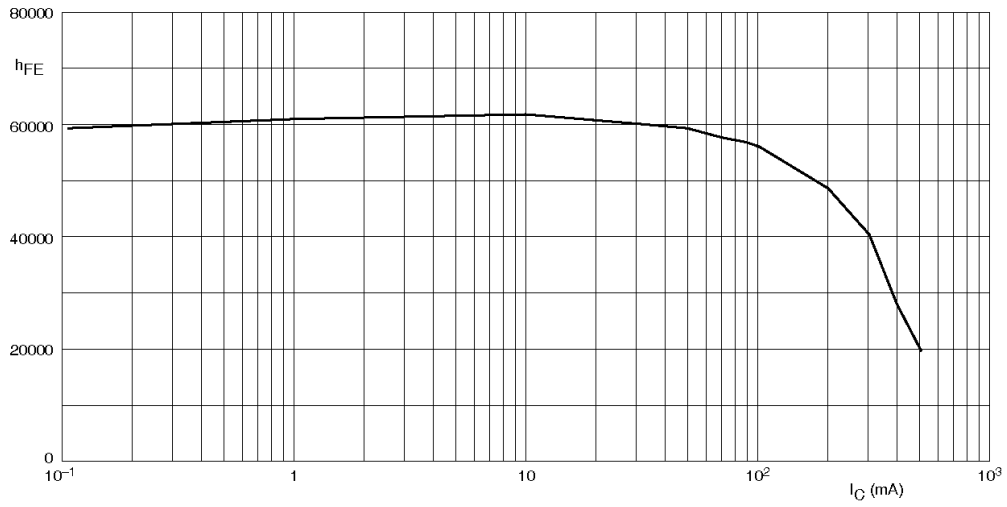
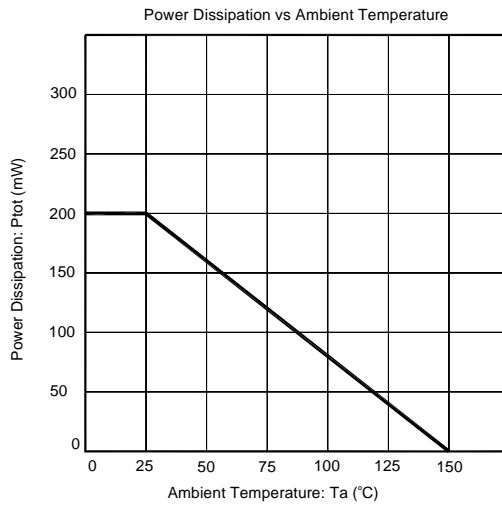
Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain					
at $V_{CE} = 5\text{ V}$, $I_C = 1\text{ mA}$	BCV27 BCV47 h_{FE}	4000 2000	- -	- -	- -
at $V_{CE} = 5\text{ V}$, $I_C = 10\text{ mA}$	BCV27 BCV47 h_{FE}	10000 4000	- -	- -	- -
at $V_{CE} = 5\text{ V}$, $I_C = 100\text{ mA}$	BCV27 BCV47 h_{FE}	20000 10000	- -	- -	- -
Collector Base Cutoff Current					
at $V_{CB} = 30\text{ V}$	BCV27 I_{CBO}	-	-	100	nA
at $V_{CB} = 60\text{ V}$	BCV47 I_{CBO}	-	-	100	nA
Emitter Base Cutoff Current					
at $V_{EB} = 10\text{ V}$	I_{EBO}	-	-	100	nA
Collector Base Breakdown Voltage	BCV27 BCV47 $V_{(BR)CBO}$	40 80	- -	- -	V
Collector Emitter Breakdown Voltage	BCV27 BCV47 $V_{(BR)CEO}$	30 60	- -	- -	V
Emitter Base Breakdown Voltage	$V_{(BR)EBO}$	10	-	-	V
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	-	-	1	V
at $I_C = 100\text{ mA}$, $I_B = 0.1\text{ mA}$					
Base Emitter Saturation Voltage	$V_{BE(sat)}$	-	-	1.5	V
at $I_C = 100\text{ mA}$, $I_B = 0.1\text{ mA}$					
Base Emitter On-state Voltage	$V_{BE(on)}$	-	-	1.4	V
at $I_C = 10\text{ mA}$, $V_{CE} = 5\text{ V}$					
Transition Frequency	f_T	-	220	-	MHz
at $V_{CE} = 5\text{ V}$, $I_C = 30\text{ mA}$, $f = 100\text{ MHz}$					



SEMTECH ELECTRONICS LTD.
Subsidiary of Sino-Tech International (BVI) Limited

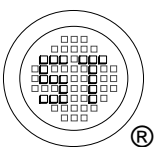


Dated : 18/08/2007



V_{CE} = 2 V.

DC current gain; typical values.



SEMTECH ELECTRONICS LTD.
 Subsidiary of Sino-Tech International (BVI) Limited



Dated : 18/08/2007